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September 1983 Revised May 2005

MM74HC540 • MM74HC541 Inverting Octal 3-STATE Buffer • Octal 3-STATE Buffer

General Description

The MM74HC540 and MM74HC541 3-STATE buffers utilize advanced silicon-gate CMOS technology. They possess high drive current outputs which enable high speed operation even when driving large bus capacitances. These circuits achieve speeds comparable to low power Schottky devices, while retaining the advantage of CMOS circuitry, i.e., high noise immunity, and low power consumption. Both devices have a fanout of 15 LS-TTL equivalent inputs.

The MM74HC540 is an inverting buffer and the MM74HC541 is a non-inverting buffer. The 3-STATE control gate operates as a two-input NOR such that if either $\overline{G1}$ or $\overline{G2}$ are HIGH, all eight outputs are in the high-impedance state.

In order to enhance PC board layout, the MM74HC540 and MM74HC541 offers a pinout having inputs and outputs on opposite sides of the package. All inputs are protected from damage due to static discharge by diodes to $\rm V_{CC}$ and ground.

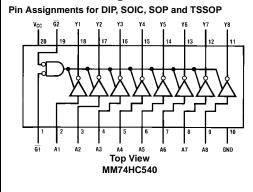
Features

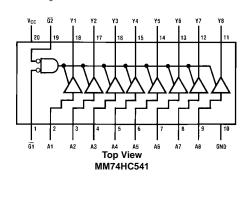
- Typical propagation delay: 12 ns
- 3-STATE outputs for connection to system buses
- Wide power supply range: 2–6V
- Low quiescent current: 80 µA maximum (74HC Series)
- Output current: 6 mA

Ordering Code:

Order Number	Package Number	Package Description
MM74HC540WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
MM74HC540SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC540MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC540N	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
MM74HC541WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
MM74HC541SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC541MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC541N	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Connection Diagrams





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Absolute Maximum Ratings(Note 1)

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(Note 2)	
Supply Voltage (V _{CC})	-0.5 to +7.0V
DC Input Voltage (V _{IN})	–1.5 to V _{CC} +1.5V
DC Output Voltage (V _{OUT})	–0.5 to V _{CC} +0.5V
Clamp Diode Current (I _{CD})	±20 mA
DC Output Current, per pin (I _{OUT})	±35 mA
DC V _{CC} or GND Current,	
per pin (I _{CC})	±70 mA
Storage Temperature Range (T _{STG})	-65°C to +150°C
Power Dissipation (P _D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T _L)	
(Soldering 10 seconds)	260°C

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V _{CC})	2	6	V
DC Input or Output Voltage			
(V _{IN} , V _{OUT})	0	V_{CC}	V
Operating Temperature Range (T_A)	-40	+85	°C
Input Rise or Fall Times			
$(t_r, t_f) V_{CC} = 2.0V$		1000	ns
$V_{CC} = 4.5V$		500	ns
$V_{CC} = 6.0V$		400	ns
Note 1: Absolute Maximum Ratings are those	values be	eyond whi	ch dam-

age to the device may occur. Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: – 12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	Vcc	$T_A = 25^{\circ}C$		$T_A = -40$ to $85^{\circ}C$	T _A = -55 to 125°C	Units
	Farameter	Conditions	*cc	Тур		Guaranteed L	imits	Units
VIH	Minimum HIGH Level		2.0V		1.5	1.5	1.5	V
	Input Voltage		4.5V		3.15	3.15	3.15	V
			6.0V		4.2	4.2	4.2	V
V _{IL}	Maximum LOW Level		2.0V		0.5	0.5	0.5	V
	Input Voltage		4.5V		1.35	1.35	1.35	V
			6.0V		1.8	1.8	1.8	V
V _{OH}	Minimum HIGH Level	$V_{IN} = V_{IH}$ or V_{IL}						
	Output Voltage	$\left I_{OUT}\right \leq 20 \ \mu A$	2.0V	2.0	1.9	1.9	1.9	V
			4.5V	4.5	4.4	4.4	4.4	V
			6.0V	6.0	5.9	5.9	5.9	V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$						
		$ I_{OUT} \le 6.0 \ mA$	4.5V	4.2	3.98	3.84	3.7	V
		$ I_{OUT} \le 7.8 \text{ mA}$	6.0V	5.7	5.48	5.34	5.2	V
V _{OL}	Maximum LOW Level	$V_{IN} = V_{IH}$ or V_{IL}						
	Output Voltage	$\left I_{OUT}\right \leq 20 \ \mu A$	2.0V	0	0.1	0.1	0.1	V
			4.5V	0	0.1	0.1	0.1	V
			6.0V	0	0.1	0.1	0.1	V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$						
		$ I_{OUT} \le 6.0 \ mA$	4.5V	0.2	0.26	0.33	0.4	V
		$ I_{OUT} \le 7.8 \ mA$	6.0V	0.2	0.26	0.33	0.4	
I _{IN}	Maximum Input	$V_{IN} = V_{CC}$ or GND	6.0V		±0.1	±1.0	±1.0	μA
	Current							
I _{OZ}	Maximum 3-STATE	$V_{IN} = V_{IH}$ or V_{IL} , $\overline{G} = V_{IH}$	6.0V		±0.5	±5	±10	μA
	Output Leakage	$V_{OUT} = V_{CC}$ or GND						
	Current							
Icc	Maximum Quiescent	V _{IN} = V _{CC} or GND	6.0V		8.0	80	160	μA
	Supply Current	$I_{OUT} = 0 \mu A$						

Note 4: For a power supply of 5V \pm 10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

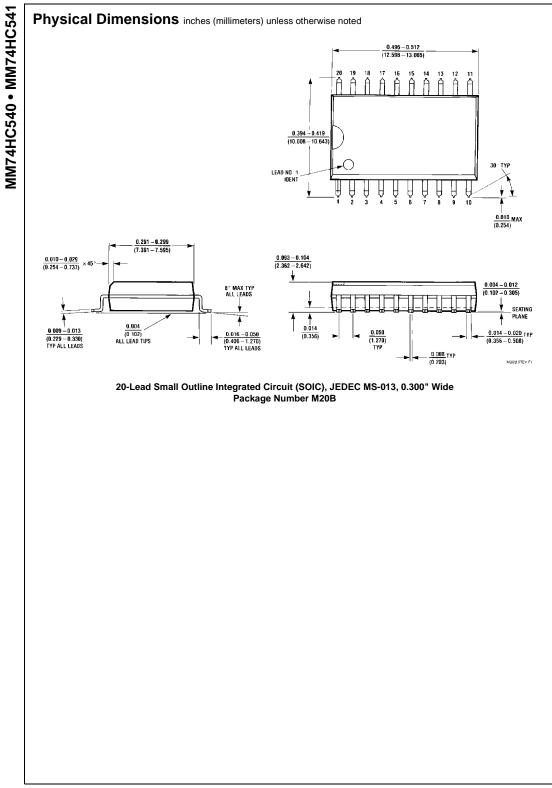
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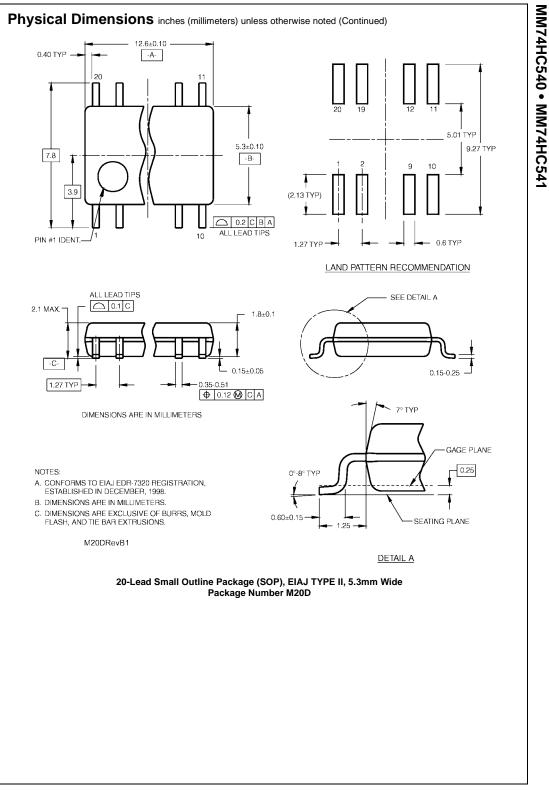
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Symb		$\frac{A = 25^{\circ}C, t_r = t_f = 6 \text{ ns}}{Parameter}$		Conditions			Guaranteed Limit	Units	
t _{PHL} , t _{PLH}	Maximum Propagation Delay (540)	Maximum Propagation		C _L = 45 pF			18	ns	
t _{PHL} , t _{PLH} Maximum Propagati Delay (541) t _{PZH} , t _{PZL} Maximum Output Er Time		ı	$C_L = 45 \text{ pF}$ $R_L = 1 \text{ k}\Omega$ $C_L = 45 \text{ pF}$			14	20	ns ns	
		ble					28		
t _{PHZ} , t _{PLZ}	Maximum Output Disa	able	$R_L = 1 k\Omega$			15	25	ns	
	Time								
V _{CC} = 2 Symbol	.0V to 6.0V, $C_L = 50 \text{ pF}$, $t_r =$ Parameter	Condition	s V _{CC}		25°C	T _A = -40 to 8 Guarante		25°C Units	
t _{PHL} , t _{PLH}	Maximum Propagation	$C_L = 50 \text{ pF}$	2.0V	55	100	126	149	ns	
Del	Delay (540)	$C_L = 150 \text{ pF}$	2.0V	83	150	190	224	ns	
		C _L = 50 pF	4.5V	12	20	25	30	ns	
		$C_L = 150 \text{ pF}$	4.5V	22	30	38	45	ns	
		$C_L = 50 \text{ pF}$	6.0V	11	17	21	25	ns	
		C _L = 150 pF	6.0V	18	26	32	38	ns	
t _{PHL} , t _{PLH}	Maximum Propagation	C _L = 50 pF	2.0V	58	115	145	171	ns	
	Delay (541)	C _L = 150 pF	2.0V	83	165	208	246	ns	
		$C_L = 50 \text{ pF}$	4.5V	14	23	29	34	ns	
		C _L = 150 pF	4.5V	17	33	42	49	ns	
		C _L = 50 pF	6.0V 6.0V	11 14	20 28	25 35	29 42	ns	
++	Maximum Output Enable	$C_{L} = 150 \text{ pF}$	6.UV	14	28	35	42	ns	
t _{PZH} , t _{PZL}	Time	$R_L = 1 k\Omega$ $C_L = 50 pF$	2.0V	75	150	189	224	ns	
	11110	C _L = 50 pF C _L = 150 pF	2.0V 2.0V	100	200	252	224	ns	
		$C_{L} = 150 \text{ pF}$ $C_{I} = 50 \text{ pF}$	4.5V	100	30	38	45	ns	
		C _L = 150 pF	4.5V	30	40	50	43 60	ns	
		$C_{l} = 50 \text{pF}$	6.0V	13	26	32	38	ns	
		$C_L = 150 \text{ pF}$	6.0V	17	34	43	51	ns	
t _{PHZ} , t _{PLZ} Maximu Time	Maximum Output Disable	$R_L = 1 k\Omega$	2.0V	75	150	189	224	ns	
	Time	C _L = 50 pF	4.5V	15	30	38	45	ns	
		-	6.0V	13	26	32	38	ns	
t _{THL} , t _{TLH}	Maximum Output Rise	C _L = 50 pF	2.0V	25	60	75	90	ns	
"IHL' "ILH	and Fall Time		4.5V	7	12	15	18	ns	
'IHL' 'ILH			6.0V	6	10	13	15	ns	
'IHL' 'ILH			1	40	1			pF	
	Power Dissipation	$\overline{G} = V_{IH}$		10				pi	
C _{PD}	Power Dissipation Capacitance (Note 5)	$\overline{G} = V_{IH}$ $\overline{G} = V_{IL}$		50				pF	
		$\frac{\overline{G} = V_{IH}}{\overline{G} = V_{IL}}$			10	10	10		

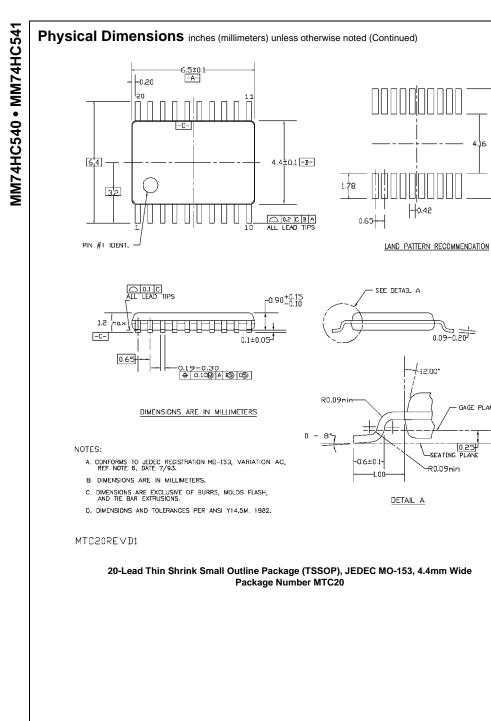
Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

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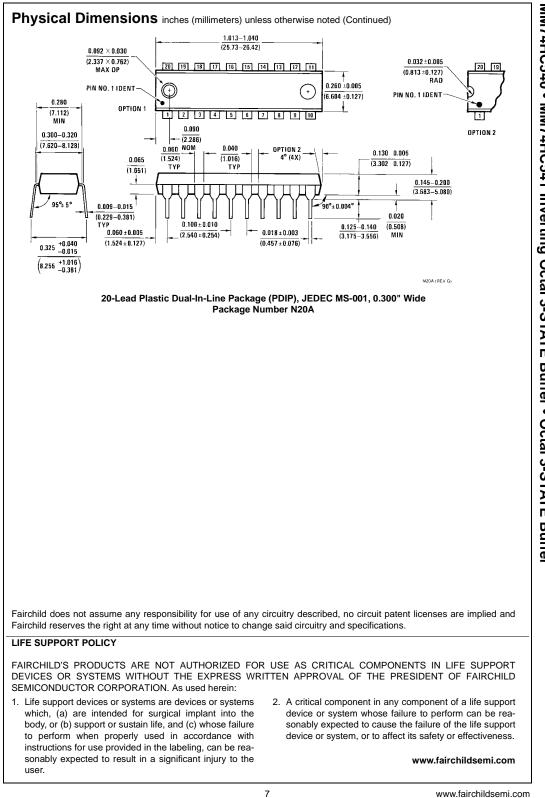
SEATING PLAN

R0.09min

GAGE PLANE

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